

積體電路之靜電放電防護設計

ESD Protection Design in CMOS Integrated Circuits

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Outlines

1. Introduction to ESD (Electrostatic Discharge) (柯明道講師)
2. Industrial Standards on ESD Events and Testing (柯明道講師)
3. Design Concepts of On-Chip ESD Protection (柯明道講師)
4. Process Issues on ESD Robustness of CMOS IC (彭政傑講師)
5. Circuit Issues on ESD Robustness of CMOS IC (彭政傑講師)
6. Whole-Chip ESD Protection Scheme (彭政傑講師)
7. ESD Protection in High-Voltage CMOS IC (莊哲豪講師)
8. CDM ESD Protection (莊哲豪講師)
9. Case Study of Recent ESD Papers (莊哲豪講師)
10. ESD Protection Design for RF Circuits (李健銘講師)
11. System Level ESD Issues (李健銘講師)
12. Latch-up Prevention in CMOS ICs (柯明道講師)

上課日期： 6/22 (二): 柯明道 Ch.1 ~ Ch. 3 6/24 (四): 彭政傑 Ch.4 ~ Ch. 6
6/29 (二): 柯明道 Ch.12(Latchup) 7/1 (四): 莊哲豪 Ch. 7 ~ Ch. 9
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